2SC2853, 2SC2854

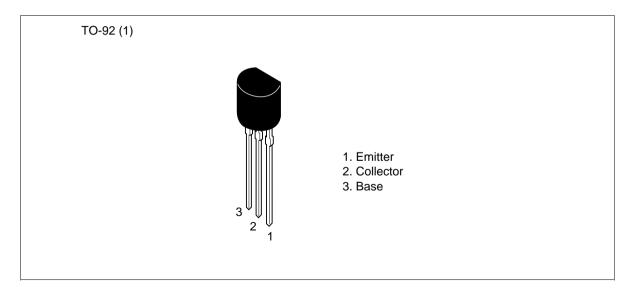
Silicon NPN Epitaxial

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Application

- Low frequency amplifier
- Complementary pair with 2SA1188 and 2SA1189

Outline





2SC2853, 2SC2854

Absolute Maximum Ratings (Ta = 25° C)

| Item | Symbol | 2SC2853 | 2SC2854 | Unit |
|------------------------------|------------------|-------------|-------------|------|
| Collector to base voltage | V _{CBO} | 90 | 120 | V |
| Collector to emitter voltage | V _{CEO} | 90 | 120 | V |
| Emitter to base voltage | V _{EBO} | 5 | 5 | V |
| Collector current | I _c | 100 | 100 | mA |
| Emitter current | Ι _Ε | -100 | -100 | mA |
| Collector power dissipation | Pc | 400 | 400 | mW |
| Junction temperature | Tj | 150 | 150 | °C |
| Storage temperature | Tstg | -55 to +150 | -55 to +150 | °C |

Electrical Characteristics (Ta = 25°C)

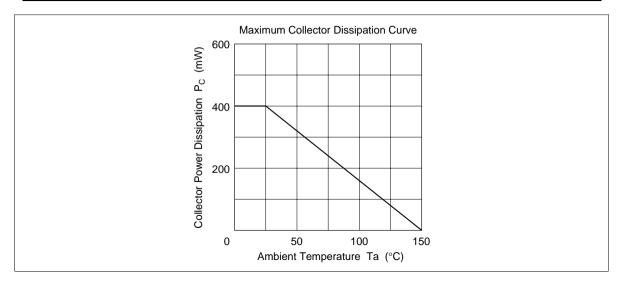
| | | 2SC2853 2SC2854 | | | | | | | |
|--|-----------------------------|-----------------|------|------|-----|------|------|------|--|
| Item | Symbol | Min | Тур | Мах | Min | Тур | Max | Unit | Test conditions |
| Collector to base breakdown voltage | $V_{\rm (BR)CBO}$ | 90 | _ | _ | 120 | _ | _ | V | $I_{c} = 10 \ \mu A, \ I_{E} = 0$ |
| Collector to emitter breakdown voltage | $V_{(\text{BR})\text{CEO}}$ | 90 | _ | _ | 120 | _ | _ | V | I_{c} = 1 mA, R_{BE} = ∞ |
| Emitter to base breakdown voltage | $V_{(BR)EBO}$ | 5 | _ | _ | 5 | _ | _ | V | $I_{\rm E} = 10 \ \mu A, \ I_{\rm C} = 0$ |
| Collector cutoff current | I _{CBO} | — | — | 0.1 | | — | 0.1 | μA | $V_{CB} = 70 \text{ V}, \text{ I}_{E} = 0$ |
| Emitter cutoff current | I _{EBO} | _ | — | 0.1 | | — | 0.1 | μA | $V_{EB} = 2 V, I_{C} = 0$ |
| DC current transfer ratio | $h_{\rm FE}^{*1}$ | 250 | — | 800 | 250 | — | 800 | | $V_{ce} = 12 \text{ V}, \text{ I}_{c} = 2 \text{ mA}^{*2}$ |
| Collector to emitter saturation voltage | $V_{\text{CE(sat)}}$ | _ | 0.05 | 0.10 | — | 0.05 | 0.10 | V | $I_{c} = 10 \text{ mA}, I_{B} = 1 \text{ mA}^{*2}$ |
| Base to emitter saturation voltage | $V_{\text{BE(sat)}}$ | _ | 0.7 | 1.0 | _ | 0.7 | 1.0 | V | - |
| Gain bandwidth product | f _T | — | 310 | — | | 310 | — | MHz | $V_{ce} = 6 \text{ V}, \text{ I}_{c} = 10 \text{ mA}$ |
| Collector output capacitance | Cob | — | 3 | — | — | 3 | — | pF | $V_{CB} = 10 \text{ V}, I_{E} = 0,$ f = 1 MHz |
| Notes: 1 The 2SC2853 and 2SC2854 are grouped by h as follows | | | | | | | | | |

Notes: 1. The 2SC2853 and 2SC2854 are grouped by $\rm h_{\rm FE}$ as follows.

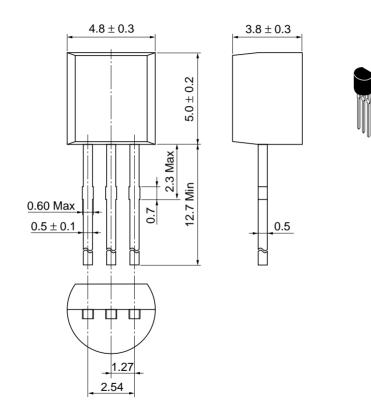
2. Pulse test **D E** 250 to 500 400 to 800

See characteristic curves of 2SC2855 and 2SC2856.

2SC2853, 2SC2854



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| Hitachi Code | TO-92 (1) |
|--------------------------|-----------|
| JEDEC | Conforms |
| EIAJ | Conforms |
| Weight (reference value) | 0.25 g |

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